

(10) **Patent No.:** US 9,209,106 B2  
(45) **Date of Patent:** Dec. 8, 2015

(58) **Field of Classification Search**  
None  
See application file for complete search history.

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(57) **ABSTRACT**

A method of assembling a semiconductor chip device is provided. The method includes providing a first circuit board that has a plurality of thermally conductive vias. A second circuit board is mounted on the first circuit board over and in thermal contact with the thermally conductive vias. The second circuit board includes first side facing the first circuit board and a second and opposite side.

**28 Claims, 5 Drawing Sheets**

(52) U.S. Cl.

U.S. Cl.

CPC ..... ***H01L 23/3677*** (2013.01); ***H01L 23/49833***  
(2013.01); ***H05K 1/0206*** (2013.01); ***H01L***  
***2224/16225*** (2013.01); ***H01L 2224/32245***  
(2013.01); ***H01L 2224/73253*** (2013.01); ***H01L***  
***2924/15311*** (2013.01); ***H05K 3/3436*** (2013.01);  
***H05K 2201/10416*** (2013.01); ***Y10T 29/49139***  
(2015.01)

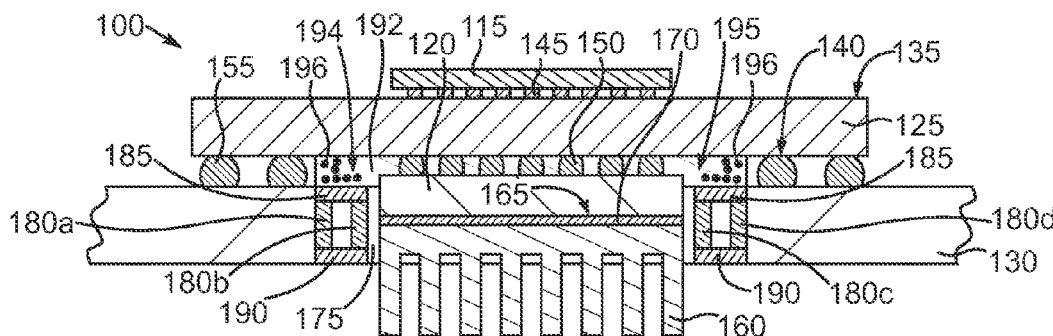


FIG. 2

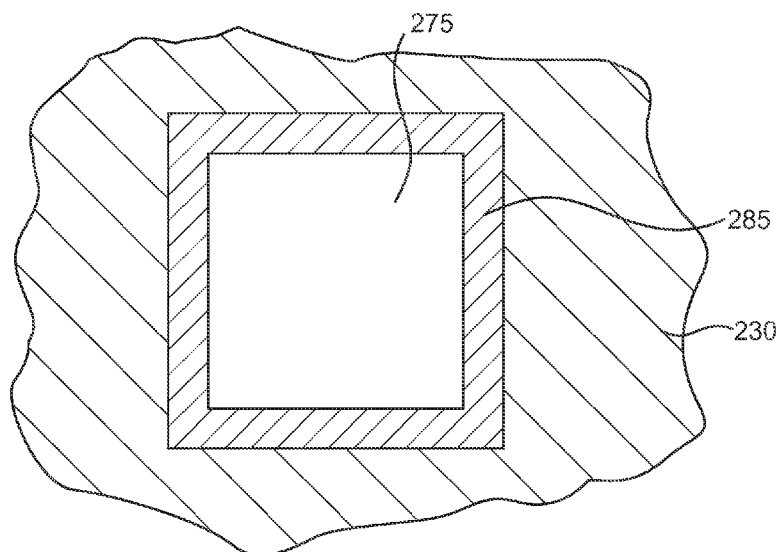


FIG. 3

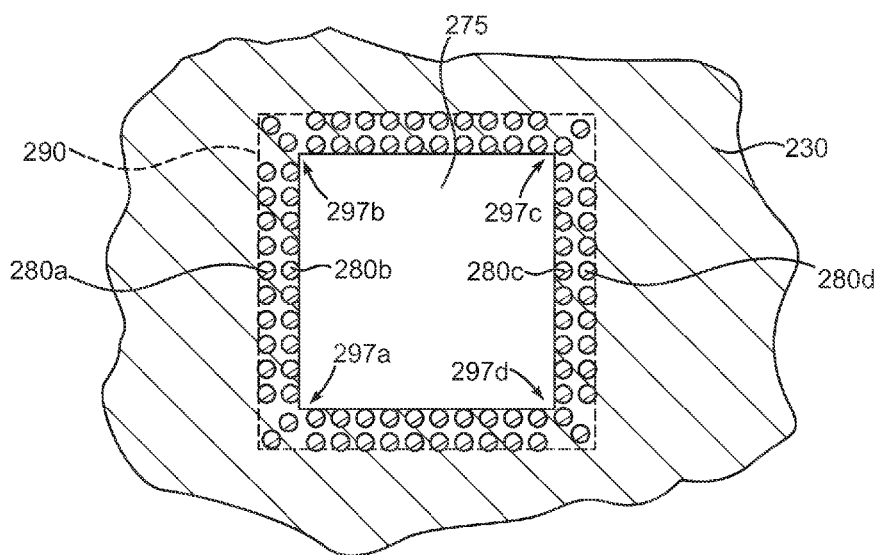


FIG. 4

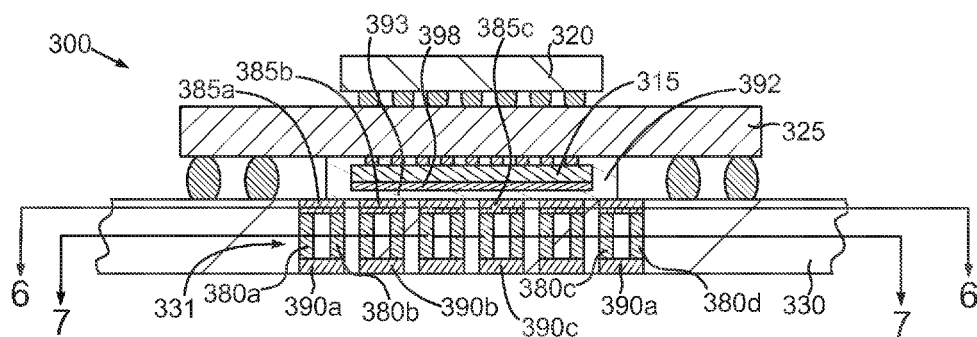


FIG. 5

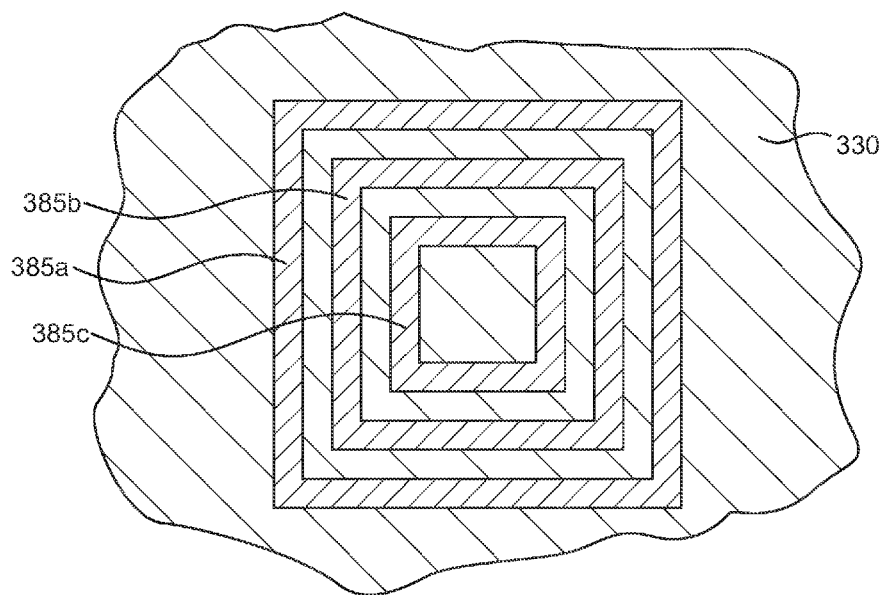


FIG. 6

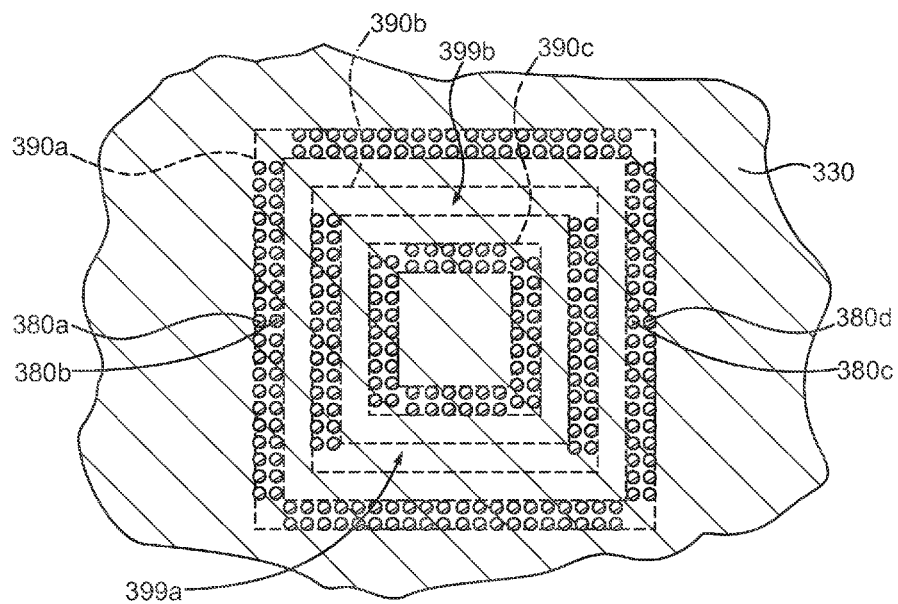


FIG. 7

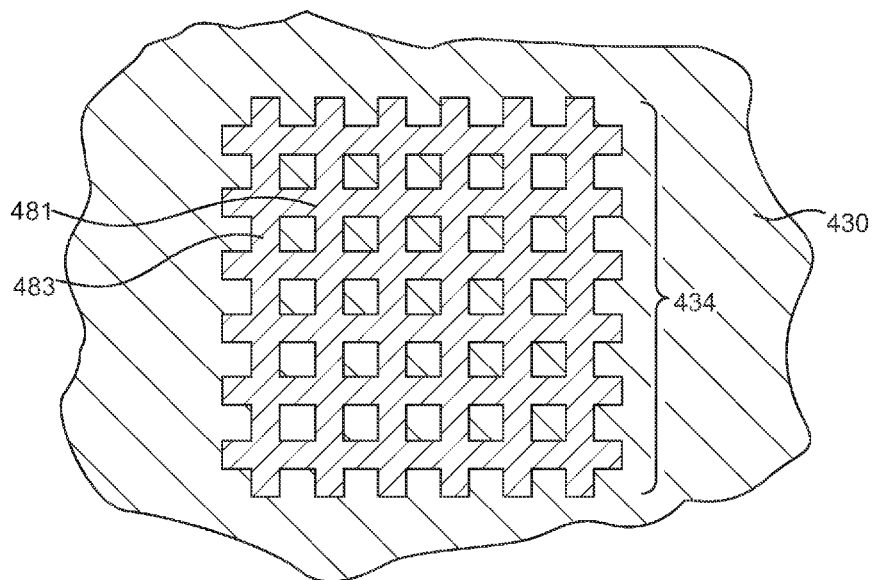


FIG. 8

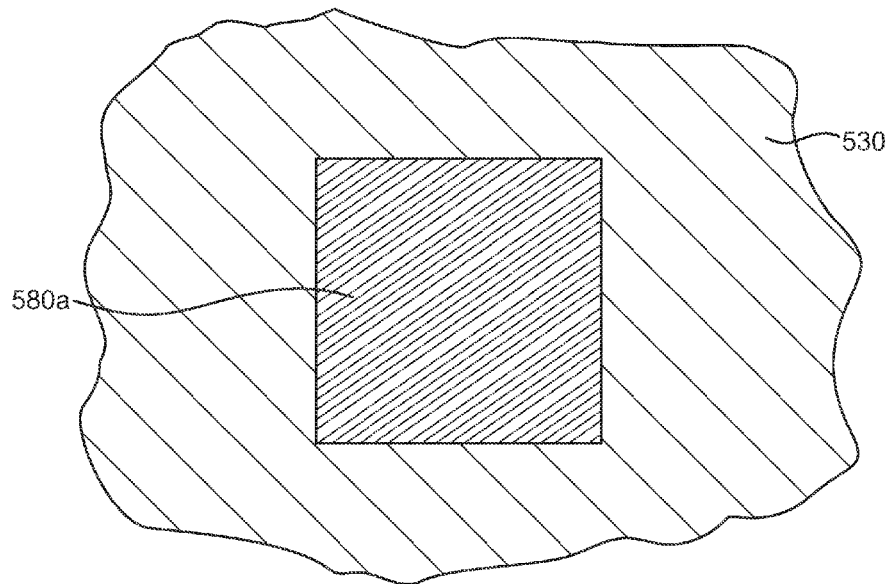


FIG. 9

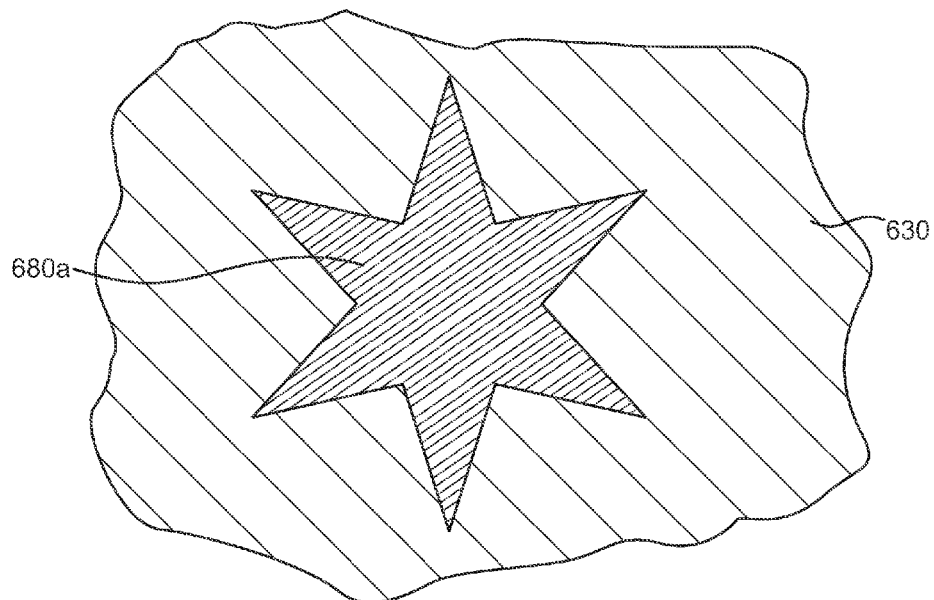


FIG. 10

1

# **THERMAL MANAGEMENT CIRCUIT BOARD FOR STACKED SEMICONDUCTOR CHIP DEVICE**

## **BACKGROUND OF THE INVENTION**

### **1. Field of the Invention**

This invention relates generally to semiconductor processing and devices, and more particularly to thermal management structures for stacked semiconductor chips and to methods of assembling the same.

### **2. Description of the Related Art**

Many current integrated circuits are formed as multiple dice on a common wafer. After the basic process steps to form the circuits on the dice are complete, the individual die are singulated from the wafer. The singulated die are then usually mounted to structures, such as circuit boards, or packaged in some form of enclosure.

One frequently-used package consists of a substrate upon which a die is mounted. The upper surface of the substrate includes electrical interconnects. The die is manufactured with a plurality of bond pads. A collection of solder joints are provided between the bond pads of the die and the substrate interconnects to establish ohmic contact. After the die is mounted to the substrate, a lid is attached to the substrate to cover the die. Some conventional integrated circuits, such as processors (e.g., CPUs, GPUs, DSPs, devices combining a GPU and CPU on a die, which are sometimes referred to as APUs, etc.), generate sizeable quantities of heat that must be transferred away to avoid device shutdown or damage. The lid serves as both a protective cover and a heat transfer pathway.

To provide a heat transfer pathway from the integrated circuit to the lid, a thermal interface material is placed on the upper surface of the integrated circuit. In an ideal situation, the thermal interface material fully contacts both the upper surface of the integrated circuit and the portion of the lower surface of the lid that overlies the integrated circuit. Conventional thermal interface materials include various types of pastes, and in some cases, a metal. Gel-type thermal interface materials consist of a polymeric matrix interspersed with thermally conductive particles, such as aluminum. More recently, designers have begun to turn to solder materials as a thermal interface material, particularly for high power-high temperature chips.

Stacked semiconductor chip devices present a host of design and integration challenges for scientists and engineers. Common problems include providing adequate electrical interfaces between the stacked semiconductor chips themselves and between the individual chips and some type of circuit board, such as a motherboard or semiconductor chip package substrate, to which the semiconductor chips are mounted. Another critical design issue associated with stacked semiconductor chips is thermal management. Most electrical devices dissipate heat as a result of resistive losses, and semiconductor chips and the circuit boards that carry them are no exception. Still another technical challenge associated with stacked semiconductor chips is testing.

Thermal management of a semiconductor chip or chips in a stacked arrangement remains a technical challenge during required electrical testing of one or more of the semiconductor chips. A given semiconductor chip in a stacked arrangement, whether the first, an intermediary or the last in the particular stack, may dissipate heat to such an extent that active thermal management is necessary in order to either prevent the one or all of the semiconductor chips in the stack from entering thermal runaway or so that one or more of the

2

semiconductor chips in the stack may be electrically tested at near or true operational power levels and frequencies.

The present invention is directed to overcoming or reducing the effects of one or more of the foregoing disadvantages.

## **SUMMARY OF EMBODIMENTS OF THE INVENTION**

In accordance with one aspect of an embodiment of the present invention, a method of assembling a semiconductor chip device is provided. The method includes providing a first circuit board that has a plurality of thermally conductive vias. A second circuit board is mounted on the first circuit board over and in thermal contact with the thermally conductive vias. The second circuit board includes first side facing the first circuit board and a second and opposite side.

In accordance with another aspect of an embodiment of the present invention, a method of manufacturing is provided that includes fabricating a plurality of thermally conductive vias in a first circuit board. A second circuit board is mounted on the first circuit board over and in thermal contact with the thermally conductive vias. The second circuit board includes first side facing the first circuit board and a second and opposite side.

In accordance with another aspect of an embodiment of the present invention, an apparatus is provided that includes a first circuit board with a plurality of thermally conductive vias. A second circuit board is mounted on the first circuit board over and in thermal contact with the thermally conductive vias. The second circuit board includes first side facing the first circuit board and a second and opposite side.

## **BRIEF DESCRIPTION OF THE DRAWINGS**

The foregoing and other advantages of the invention will become apparent upon reading the following detailed description and upon reference to the drawings in which:

FIG. 1 is a sectional view of an exemplary embodiment of a semiconductor chip device that includes two semiconductor chips connected to a circuit board mounted to another circuit board;

FIG. 2 is a sectional view like FIG. 1, but of an alternate exemplary embodiment of a semiconductor chip device that includes two semiconductor chips connected to a circuit board mounted to another circuit board;

FIG. 3 is a sectional view of FIG. 2 taken at section 3-3;

FIG. 4 is a sectional view of FIG. 2 taken at section 4-4;

FIG. 5 is a sectional view like FIG. 1, but of an alternate exemplary embodiment of a semiconductor chip device that includes two semiconductor chips connected to a circuit board mounted to another circuit board;

FIG. 6 is a sectional view of FIG. 5 taken at section 6-6;

FIG. 7 is a sectional view of FIG. 5 taken at section 7-7;

FIG. 8 is a sectional view like FIG. 6, but of an alternate exemplary circuit board and patterned metal line arrangement;

FIG. 9 is a sectional view depicting a small portion of an alternate exemplary circuit board and alternate exemplary thermal via; and

FIG. 10 is a sectional view like FIG. 9, but depicting a small portion of another alternate exemplary circuit board and another alternate exemplary thermal via.

## **DETAILED DESCRIPTION OF SPECIFIC EMBODIMENTS**

Various stacked semiconductor chip arrangements are disclosed. The disclosed embodiments incorporate a first circuit

3

board with plural thermally conductive vias that are designed to convey heat from a second circuit board mounted to the first. The second circuit board may have a bottom-mounted semiconductor chip also in thermal contact with the thermal vias. The first circuit board may include an opening to accommodate the bottom-mounted semiconductor chip and an optional heat spreader mounted to the semiconductor chip. With the thermal vias in place, the first circuit board doubles (i.e., additionally operates) as a heat spreader. Additional details will now be described.

In the drawings described below, reference numerals are generally repeated where identical elements appear in more than one figure. Turning now to the drawings, and in particular to FIG. 1, therein is shown a sectional view of an exemplary embodiment of a semiconductor chip device **100** that includes two semiconductor chips **115** and **120** connected to a circuit board **125**. The circuit board **125** may, in turn, be mounted on another circuit board **130**. The semiconductor chip **115** may be mounted to an upper side **135** of the circuit board **125** and the semiconductor chip **120** may be mounted to a lower side **140** of the circuit board **125**. The designations “upper” and “lower” are somewhat arbitrary in the context of this disclosure. The semiconductor chip **115** may be electrically connected to the circuit board **125** by way of plural interconnect structures **145**, which may be solder bumps, micro bumps, conductive pillars plus solder or other types of interconnects. Exemplary materials include copper, aluminum, gold, platinum, palladium, silver, tin, lead combinations of these or others. The semiconductor chip **120** may be electrically connected to the circuit board **125** by way of plural interconnect structures **150** which may be configured like the interconnect structures **150** and constructed of the same types of materials. Finally, the circuit board **125** may be electrically connected to the circuit board **130** by way of plural interconnect structures **155** which may be solder bumps, conductive pillars plus solder or other types of interconnects composed of the materials just described.

The semiconductor chips **115** and **120** may be any of a variety of different types of circuit devices used in electronics, such as, for example, interposers, microprocessors, graphics processors, combined microprocessor/graphics processors, application specific integrated circuits, memory devices or the like, and may be single or multi-core. The semiconductor chips **115** and **120** may be constructed of bulk semiconductor, such as silicon or germanium, or semiconductor-on-insulator materials, such as silicon-on-insulator materials or even insulator materials. Thus, the term “semiconductor chip” even contemplates insulating materials. Here, the semiconductor chip device **100** includes two semiconductor chips **115** and **120** in a stack. However, more than two may be used.

The circuit board **125** may be another semiconductor chip of the type described above, a semiconductor chip package substrate, a circuit card, or virtually any other type of printed circuit board. Although a monolithic structure could be used for the circuit board **125**, a more typical configuration will utilize a build-up design. In this regard, the circuit board **125** may consist of a central core upon which one or more build-up layers are formed and below which an additional one or more build-up layers are formed. The core itself may consist of a stack of one or more layers. So-called “coreless” designs may be used as well. The layers of the circuit board **125** may consist of an insulating material, such as various well-known epoxies or other resins interspersed with metal interconnects. A multi-layer configuration other than buildup could be used. Optionally, the circuit board **125** may be composed of well-

4

known ceramics or other materials suitable for package substrates or other printed circuit boards.

The circuit board **130** may be a system board, a circuit card or virtually any other type of printed circuit board. Like the circuit board **125**, the circuit board could be monolithic or a laminate. If a laminate, well-known epoxy resins impregnated with glass or other fillers may be used. The circuit boards **125** and **130** may include multiple layers of metallization (not shown). The semiconductor chips **115** and **120** may also include multiple layers of metallization (again not shown).

Various mechanisms are provided to transfer heat from various portions of the semiconductor chip device **100**. For example, a heat sink **160** may be connected to a lower side **165** of the semiconductor chip **120** by way of a thermal interface material layer **170**. The thermal interface material layer **170** may be composed of a variety of different types of thermal interface material suitable for thermal management, such as, silicone rubber, silicone greases, acrylic polymers or the like. Even metallic materials, such as indium, gallium, various solders or the like could be used. The heat sink **160** may take on a myriad of configurations such as the heat-finned heat spreader arrangement as shown or virtually any other type of heat transfer device design. If desired, the heat sink **160** may include a vapor chamber and/or a solid state thermoelectric cooler. Various types of materials suitable for heat transfer devices may be used, such as copper, nickel, aluminum, steel, combinations of these or the like. Somewhat more exotic materials, such as diamond or sapphire, could also be used for extreme thermal environments. To accommodate the spatial positioning of the semiconductor chip **120** and the heat sink **160**, the circuit board **130** may be provided with a suitable opening **175** in which the semiconductor chip **120** and the heat sink **160** project. It is anticipated that the circuit board **130** may be fabricated along with the opening **175** in a variety of ways. For example, either material removal or deliberate patterning techniques may be used to establish the opening **175**. In this regard, the circuit board **130** could be fabricated as a relatively planar structure and thereafter a suitable material removal process may be used in order to form the opening **175**. Again, electrical routing structures (not visible) would have to be placed outside the location of where the opening **175** is intended to be made. The material removal could be by chemical etch, laser ablation or other material removal techniques. On the other hand, if a patterning technique is used to establish the opening **175**, then the opening **175** may be formed as the circuit board **130** is formed. This may be accomplished for example where the circuit board **130** is of a buildup design by some sort of hard masking in the location where the opening **175** is to be formed during each subsequent insulating material deposition step so that material is not positioned where the opening **175** is intended to be. Obviously such hard masking would have to be by way of a material that does not readily wet to whatever epoxies or other types of organic compounds that are used to form the various buildup layers that make up the circuit board **130** in that context. Since the opening **175** does eliminate some portions of the circuit board **130** that would otherwise be available for the routing and traces, the loss of available circuit board volume will have to be compensated during layout of the conductor traces for the circuit board **130**.

To further enhance the transfer of heat from at least the circuit board **125**, the circuit board **130** may be provided with plural thermally conductive vias (hereinafter “thermal vias”), four of which are visible in FIG. 1 and labeled **180a**, **180b**, **180c** and **180d**. The thermal vias **180a**, **180b**, **180c** and **180d** (and other disclosed alternatives) may be electrically floating

5

and thus non-functional, or operable to be at some bias level and thus electrically functional. As will become apparent in subsequent figures, there may be many more than just four of the thermal vias **180a**, **180b**, **180c** and **180d**. The thermal vias **180a**, **180b**, **180c** and **180d** may be capped above by a patterned metal line **185** and below by another patterned metal line **190** that are both formed on or in the circuit board **130**. The thermal vias **180a**, **180b**, **180c** and **180d** and the patterned metal lines **185** and **190**, and any disclosed alternatives thereto, may be composed of a variety of thermally conducting materials, such as solders, metals and alloys. Exemplary materials include copper, aluminum, gold, platinum, palladium, silver, tin, lead combinations of these or others. Well-known fabrication processes may be used to form the thermal vias **180a**, **180b**, **180c** and **180d** and the patterned metal lines **185** and **190**, such as plating, chemical vapor deposition, physical vapor deposition or others. Via openings may be etched, laser drilled or otherwise formed. The arrangement and number of the thermal vias **180a**, **180b**, **180c** and **180d** and the patterned metal lines **185** and **190** may take on an enormous variety of configurations. A few of these exemplary configurations will be illustrated in subsequent figures.

A thermally conductive pathway between the circuit board **125** and the thermal vias **180a**, **180b**, **180c** and **180d** is established by positioning an underfill material layer **192** between the circuit board **125** and the circuit board **130** but in thermal contact with the patterned metal line **185**. The underfill material layer **195** may be composed of a variety of materials suitable for underfill such as epoxy resin with or without silica fillers and phenol resins or the like. Two examples are types **8437-2** and **2BD** available from Namics.

If desired, the thermal conductivity of the regions **194** and **195** of the underfill layer **192** proximate the thermal vias **180a** and **180b** and the thermal vias **180c** and **180d**, respectively, may be enhanced by impregnating or otherwise dispersing thermally conductive particles **196**, such as nano spheres or other particles composed of gold, copper, silver or other thermally conductive materials. It should be understood that the particles **196** could be dispersed around the entire perimeter of the semiconductor chip **120** if desired. If the particles **196** are used, care should be exercised to avoid shorting the interconnect structures **150** and **155**. The particles **196** could be used in any of the disclosed embodiments.

An alternate exemplary embodiment of a semiconductor chip device **200** may be understood by referring now to FIG. **2**, which is a sectional view similar to the sectional view depicted in FIG. **1**. The semiconductor chip device **200** shares many attributes of the semiconductor chip device embodiment **100** depicted in FIG. **1** and described above. Thus, the device **200** may include semiconductor chips **215** and **220** mounted to a circuit board **225** and the circuit board **225** may be in turn mounted to a circuit board **230**. The semiconductor chips **215** and **220** and the circuit boards **225** and **230** may be configured like the corresponding components of the semiconductor chip device **100** described above in conjunction with FIG. **1**. Here, however, the relative positions of the semiconductor chips **215** and **220** are swapped, that is, the semiconductor chip **220** is mounted on the upper surface **235** of the circuit board **225** and the semiconductor chip **215** is mounted on the lower surface **240** of the circuit board **225**. The positions of the interconnect structures **245** and **250** are also flip-flopped from the positions of the interconnect structures **145** and **150** in FIG. **1**. In this case, the heat sink **260** is also mounted to the semiconductor chip **220**, but due to its position, does not project through the opening **275** in the circuit board **230**. Depending upon the thickness of the semiconductor chip **215** and the height of the interconnect struc-

6

tures **245**, some or all of semiconductor chip **215** may project into the opening **275** as shown.

Like the circuit board **130**, the circuit board **230** may be provided with thermal vias **280a**, **280b**, **280c** and **280d** and patterned metal lines **285** and **290**. Again, it should be understood that the thermal vias **280a**, **280b**, **280c** and **280d** may number more than four.

Additional details of the patterned metal line **285** and the thermal vias **280a**, **280b**, **280c** and **280d** may be understood by referring now to FIGS. **3** and **4**. FIG. **3** is a sectional view of FIG. **2** taken at section **3-3** and FIG. **4** is a sectional view of FIG. **2** taken at section **4-4**. Only portions of the circuit board **230** are depicted in FIGS. **3** and **4**. The following description of thermal vias **280a**, **280b**, **280c** and **280d** and the patterned metal line **285** will be illustrative also of the thermal vias **180a**, **180b**, **180c** and **180d** and the patterned metal line **185** associated with the circuit board **130** depicted in FIG. **1**. Turning first to FIG. **3**, the patterned metal line **285** is shown in section and appears as a square or rectangular frame structure that surrounds the opening **275** in the circuit board **230**. In this illustrative embodiment, the patterned metal line **285** may be a continuous frame member as depicted. However, the skilled artisan will appreciate that a segmented design may also be used. The patterned metal line **285** may be square, rectangular or have virtually any other footprint. The opening **275** may similarly be square, rectangular or have virtually any other footprint.

An exemplary arrangement of the thermal vias **280a**, **280b**, **280c** and **280d** will now be described in conjunction with FIG. **4**. In this illustrative embodiment, the thermal vias **280a**, **280b**, **280c** and **280d** and the multitude of others that are not separately labeled may be arranged around the perimeter of the opening **275** as shown. Here, the thermal vias **280a** and **280b**, for example, are arranged in pairs two abreast. However, the skilled artisan will appreciate that the number and spatial arrangement of thermal vias **280a**, **280b**, **280c** and **280d** may be more than two and in a variety of different spatial arrangements. Note that the portions of the circuit board **230** near the corners **297a**, **297b**, **297c** and **297d** of the opening **275** may be populated with some of the thermal vias as desired. It should be understood that the patterned metal line **290** depicted in section in FIG. **2** and shown in dashed in FIG. **4** may have the same footprint as the patterned metal line **285** shown in FIG. **3** or some different configuration as desired.

Another alternate exemplary embodiment of a semiconductor chip device **300** may be understood by referring now to FIG. **5**, which is a sectional view. This illustrative embodiment of a semiconductor chip device **300** shares several attributes with the other embodiments of the chip device **100** and **200** described above, namely, the mounting of the semiconductor chips **315** and **320** to the circuit board **325**. Here, however, the circuit board **325** may be mounted to a circuit board **330** that does not include an opening like the openings **175** and **275** depicted in FIGS. **1** and **2** to accommodate a bottom-mounted heat sink. Instead, the region **331** beneath the semiconductor chip **315** is populated by an array of thermal vias, a few of which are labeled, **380a**, **380b**, **380c** and **380d**, that may be capped above by respective patterned metal lines **385a**, **385b** and **385c** and capped below by corresponding patterned metal lines **390a**, **390b** and **390c**. A thermally conductive pathway between the semiconductor chip **315** and the thermal vias **380a**, **380b**, **380c** and **380d** may be established by positioning the thermal interface material **392** between the circuit board **325** and the circuit board **330** and in between a gap **393** that may exist between the semiconductor chip **315** and the circuit board **330** and in particular between

a thermal pad **398** which may be attached to the semiconductor chip **315** to provide an improved thermal interface. In addition, the thermal interface material **392** is in thermal contact with at least some portion of the thermal vias **380a**, **380b**, **380c** and **380d** by way of, for example, the patterned metal lines **385a**, **385b** and **385c**.

More details regarding the patterned metal lines **385a**, **385b** and **385c** and the thermal vias **380a**, **380b**, **380c** and **380d** may be understood by referring now to FIGS. 6 and 7 which are sectional views of FIG. 5 taken at sections 6-6 and 7-7, respectively. Attention is turned first to FIG. 6, which shows a portion of the circuit board **330** and the patterned metal lines **385a**, **385b** and **385c** in section. Here, the patterned metal lines **385a**, **385b** and **385c** may be patterned as concentric rectangular frame members as shown. However, as noted elsewhere herein, the patterned metal lines **385a**, **385b** and **385c** may be segmented and patterned with other than square or rectangular shapes as desired. In addition, the number of patterned metal lines **385a**, **385b** and **385c** may be other than three.

The exemplary array of thermal vias **380a**, **380b**, **380c** and **380d** may be understood by referring now to FIG. 7. As FIG. 7 illustrates, the number of thermal vias **380a**, **380b**, **380c** and **380d** may be substantially more numerous than the four that are separately labeled **380a**, **380b**, **380c** and **380d** in FIGS. 5 and 7. Here, some or all of the thermal vias **380a**, **380b**, **380c** and **380d** may be positioned around the perimeters of the patterned metal lines **390a**, **390b** and **390c**, which are shown in dashed.

It may be desirable to thermally map the heat output of the semiconductor chip **315** and the circuit board **335** depicted in FIG. 5 and then concentrate the thermal vias **380a**, **380b**, **380c** and **380d** in those places exhibiting the highest heat flux. Conversely, areas that do not exhibit significant heat flux may be devoid of thermal vias **380a**, **380b**, **380c** and **380d** as desired. Thus, the regions **398a** and **398b** of the circuit board **330** may be relatively devoid of the thermal vias **380a**, **380b**, **380c** and **380d** whereas the other areas may be highly concentrated with thermal vias **380a**, **380b**, **380c** and **380d** as shown.

As noted elsewhere herein, the patterned metal lines capping the various thermal vias from above and below may take on a variety of configurations. In the foregoing illustrative embodiments, the patterned metal lines have been illustrated as square or rectangular frame members. However, FIG. 8 depicts a sectional view of an alternate exemplary embodiment of a circuit board **430** that includes a patterned metal line array **434** that serves the function of, for example, the patterned metal lines **385a**, **385b** and **385c** and depicted in FIG. 6 or the patterned metal line **285** depicted in FIG. 3 or even the patterned metal lines **285a**, **285b** and **285c** or **190** described above. Here, the patterned metal line array **434** may be patterned in the waffle-like arrangement with intersecting lines **481** and **483** as shown. This type of arrangement may provide enhanced thermal conductivity between adjacent patterned metal lines.

In the foregoing illustrative embodiments, the thermal vias **180a**, **280a**, etc., are fabricated with a circular footprint. However, due to the tremendous flexibility of prevailing lithography, laser drilling, and material deposition processes, thermal via size and shape may be tailored to produce a variety of shapes. For example FIG. 9 depicts a sectional view of a circuit board **530** that includes plural thermal vias, one of which is visible, labeled **580a** and fabricated with a square footprint. In yet another example, FIG. 10 depicts a sectional view of a circuit board **630** that includes plural thermal vias,

one of which is visible, labeled **680a** and fabricated with a star-shaped footprint. These thermal vias **580a** and **680a** represent just a few possibilities.

Any of the exemplary embodiments disclosed herein may be embodied in instructions disposed in a computer readable medium, such as, for example, semiconductor, magnetic disk, optical disk or other storage medium or as a computer data signal. The instructions or software may be capable of synthesizing and/or simulating the circuit structures disclosed herein. In an exemplary embodiment, an electronic design automation program, such as Cadence APD, Encore or the like, may be used to synthesize the disclosed circuit structures. The resulting code may be used to fabricate the disclosed circuit structures.

While the invention may be susceptible to various modifications and alternative forms, specific embodiments have been shown by way of example in the drawings and have been described in detail herein. However, it should be understood that the invention is not intended to be limited to the particular forms disclosed. Rather, the invention is to cover all modifications, equivalents and alternatives falling within the spirit and scope of the invention as defined by the following appended claims.

What is claimed is:

1. A method of assembling a semiconductor chip device, comprising:

providing a first circuit board including a plurality of thermally conductive vias;

mounting a second circuit board on the first circuit board over and in thermal contact with the thermally conductive vias, the second circuit board including first side facing the first circuit board and a second and opposite side; and

coupling a first semiconductor chip on the first side of the second circuit board over and in thermal contact with the thermally conductive vias, at least a portion of the first semiconductor chip extending beyond the first side of the second circuit board.

2. The method of claim 1, comprising placing an underfill material between and in thermal contact with the second circuit board and at least some of the thermally conductive vias.

3. The method of claim 2, wherein the underfill material includes thermally conductive particles proximate at least some of the thermally conductive vias.

4. The method of claim 1, wherein the first circuit board includes an opening, the thermally conductive vias being arranged around a perimeter of the opening.

5. The method of claim 4, wherein at least a portion of the first semiconductor chip is positioned in the opening.

6. The method of claim 4, comprising coupling a heat sink to the first semiconductor chip, at least a portion of one or both of the first semiconductor chip and the heat sink being positioned in the opening.

7. The method of claim 1, comprising coupling a first semiconductor chip to the first side of the second circuit board over and in thermal contact with the thermally conductive vias, and a second semiconductor chip to the second side of the second circuit board.

8. The method of claim 1, wherein the first circuit board comprises a first plurality of patterned metal lines coupled to first ends of the thermally conductive vias and a second plurality of patterned metal lines coupled to second ends of the thermally conductive vias.

9. The method of claim 1, wherein the thermally conductive vias are electrically non-functional.

9

10. A method of manufacturing, comprising:  
 fabricating a plurality of thermally conductive vias in a first circuit board;  
 mounting a second circuit board on the first circuit board over and in thermal contact with the thermally conductive vias, the second circuit board including first side facing the first circuit board and a second and opposite side; and  
 coupling a first semiconductor chip on the first side of the second circuit board over and in thermal contact with the thermally conductive vias, at least a portion of the first semiconductor chip extending beyond the first side of the second circuit board.
11. The method of claim 10, comprising placing an underfill material between and in thermal contact with the second circuit board and at least some of the thermally conductive vias.
12. The method of claim 11, wherein the underfill material includes thermally conductive particles proximate at least some of the thermally conductive vias.
13. The method of claim 10, comprising fabricating an opening in the first circuit board and arranging the thermally conductive vias around a perimeter of the opening.
14. The method of claim 13, wherein at least a portion of the first semiconductor chip is positioned in the opening.
15. The method of claim 13, comprising coupling a heat sink to the first semiconductor chip, at least a portion of one or both of the first semiconductor chip and the heat sink being positioned in the opening.
16. The method of claim 10, comprising coupling a first semiconductor chip to the first side of the second circuit board over and in thermal contact with the thermally conductive vias, and a second semiconductor chip to the second side of the second circuit board.
17. The method of claim 10, comprising forming a first plurality of patterned metal lines coupled to first ends of the thermally conductive vias and a second plurality of patterned metal lines coupled to second ends of the thermally conductive vias.
18. The method of claim 10, comprising forming the thermally conductive vias using instructions stored in a computer readable medium.

10

19. The method of claim 10, wherein the thermally conductive vias are electrically non-functional.
20. An apparatus, comprising:  
 a first circuit board having a plurality of thermally conductive vias;  
 a second circuit board mounted on the first circuit board over and in thermal contact with the thermally conductive vias, the second circuit board including first side facing the first circuit board and a second and opposite side; and  
 a first semiconductor chip coupled on the first side of the second circuit board over and in thermal contact with the thermally conductive vias, at least a portion of the first semiconductor chip extending beyond the first side of the second circuit board.
21. The apparatus of claim 20, comprising an underfill material positioned between and in thermal contact with the second circuit board and at least some of the thermally conductive vias.
22. The apparatus of claim 21, wherein the underfill material includes thermally conductive particles proximate at least some of the thermally conductive vias.
23. The apparatus of claim 20, wherein at least a portion of the first semiconductor chip is positioned in the opening.
24. The apparatus of claim 20, wherein the first circuit board includes an opening, the thermally conductive vias being arranged around a perimeter of the opening.
25. The apparatus of claim 24, comprising a heat sink coupled to the first semiconductor chip, at least a portion of one or both of the first semiconductor chip and the heat sink being positioned in the opening.
26. The apparatus of claim 20, comprising a first semiconductor chip coupled to the first side of the second circuit board over and in thermal contact with the thermally conductive vias, and a second semiconductor chip coupled to the second side of the second circuit board.
27. The apparatus of claim 20, comprising a first plurality of patterned metal lines coupled to first ends of the thermally conductive vias and a second plurality of patterned metal lines coupled to second ends of the thermally conductive vias.
28. The apparatus of claim 20, wherein the thermally conductive vias are electrically non-functional.

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